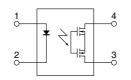
# Panasonic

### C×R type, VSSOP package, 60V and 100 V load voltage

Photo MOS<sup>®</sup> RFVSSOP 1 Form A C×R (AQY22000T)



mm inch



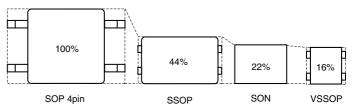
**RoHS compliant** 

# FEATURES

1. Miniature VSSOP package

4.6 mm<sup>2</sup> mounting area achieved. Approx 29% less than previous product (SON type).

Contributes to the miniaturization of instruments and higher density mounting.



#### 2. Load voltage: 60 V and 100 V

#### 3. Low C×R

Low on resistance and low output capacitance available • 60 V load voltage: AQY222R2T

Output capacitance: 27 pF (typical), On resistance: 0.8Ω (typical) • 100 V load voltage: AQY225R3T

Output capacitance: 5.8 pF (typical), On resistance: 8.8 $\Omega$  (typical)

# **TYPICAL APPLICATIONS**

Measuring and testing equipment
IC tester, Probe card, Board tester and other testing equipment
Telecommunication equipment

\*Does not support automotive applications.

## TYPES

Туре	Output rating*1		Part No. (Tape and	Packing quantity in the	
	Load voltage	Load current	Picked from the 1 and 4-pin side	Picked from the 2 and 3-pin side	tape and reel
AC/DC dual use	New 60 V	400 mA	AQY222R2TY	AQY222R2TW	1,000 pcs.
AC/DC dual use	New 100 V	120 mA	AQY225R3TY	AQY225R3TW	1,000 pcs.

Notes: \*1. Indicate the peak AC and DC values.

\*2. Only tape and reel package is available.

For space reasons, only "2R2" or "5R3" is marked on the product as the part number.

## RATING

#### 1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY222R2T	AQY225R3T	Remarks
Input side	LED forward current	lF	50 mA		
	LED reverse voltage	VR	5 V		
	Peak forward current	IFP	1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW		
Output side	Load voltage (peak AC)	VL	60 V	100 V	
	Continuous load current	L	0.4 A	0.12 A	Peak AC, DC
	Peak load current	Ipeak	1.2 A	0.3 A	100 ms (1shot), V∟ = DC
	Power dissipation	Pout	250 mW		
Total power dissipation		Ρτ	300 mW		
I/O isolation voltage		Viso	200 V AC		
Operating temperature		Topr	<b>−40°C to +85°C</b> −40°F to +185°F		Non-condensing at low temperatures
Storage temperature		Tstg	-40°C to +100°C -40°F to +212°F		

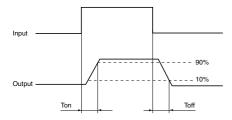
#### 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY222R2T	AQY225R3T	Condition	
Input LED LED LED	LED operate	Typical	IFon	0.4 mA		AQY222R2T: I∟ = 400 mA AQY225R3T: I∟ = 80 mA
	current	Maximum		3 mA		
	LED turn off	Minimum	Foff	0.1 mA		
	current	Typical		0.35 mA		
	LED dropout	Typical	VF	1.14 V (1.35 V at I⊧ = 50 mA)		— I⊧ = 5 mA
	voltage	Maximum	VF	1.5 V		
Output Output capac	On resistance	Typical	Ron	0.8 Ω	8.8 Ω	AQY222R2T: I⊧ = 5 mA, I⊾ = 400 mA AQY225R3T: I⊧ = 5 mA, I⊾ = 80 mA
	On resistance	Maximum		1.25 Ω	14 Ω	Within 1 s on time
	Output capacitance	Typical	Cout	27 pF	5.8 pF	IF = 0 mA, VB = 0 V, f = 1 MHz
		Maximum		40 pF	8 pF	IF = 0 IIIA, VB = 0 V, I = 1 IIIIAZ
	Off state leakage current	Typical	h .	—	0.01 nA	I⊧ = 0 mA, V∟ = Max.
		Maximum	Leak	10 nA*		$\int I^{\mu} = 0 IIIA, V^{\mu} = IVIAX.$
Transfer characteris- tics	Turn on time**	Typical	Ton	0.12 ms	0.04 ms	
		Maximum	Ion	0.5 ms		AQY222R2T: I⊧ = 5 mA, VL = 10 V, RL = 100 Ω
	Turn off time**	Typical	Toff	0.08 ms	0.05 ms	AQY225R3T: I⊧ = 5 mA, VL = 10 V, RL = 125 Ω
		Maximum	loff	0.2 ms		
	I/O capacitance	Typical	Ciso	0.4 pF		
		Maximum	Uiso	1.5 pF		$-f = 1 \text{ MHz}, V_B = 0 \text{ V}$

Notes: 1. Please refer to the "Schematic and Wiring Diagrams" for connection method.

2. Variation possible through combinations of output capacitance and on resistance. For more information, please contact our sales office in your area.

\*Available as custom orders (1 nA or less) \*\*Turn on/Turn off time



## **RECOMMENDED OPERATING CONDITIONS**

Please obey the following conditions to ensure proper this device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED forward current	F	5	mA

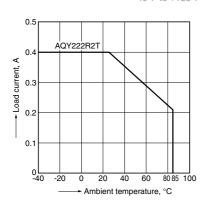
#### ■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

## **REFERENCE DATA**

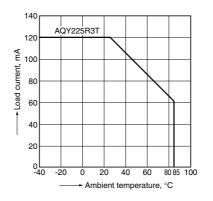
1.-(1) Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



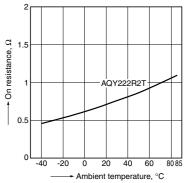
1.-(2) Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



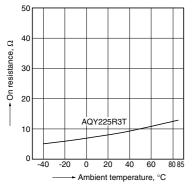
2.-(1) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: 10V (DC) Continuous load current: Max. (DC)



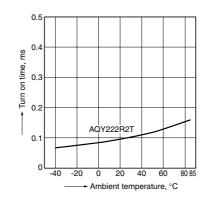
2.-(2) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 80mA (DC)



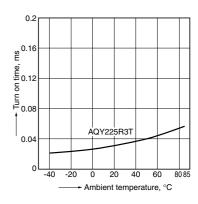
3.-(1) Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 100mA (DC)



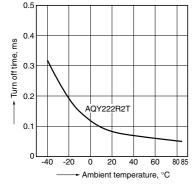
3.-(2) Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 80mA (DC)



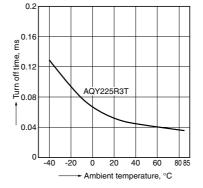
4.-(1) Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 100mA (DC)

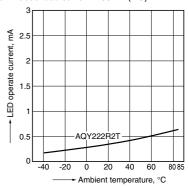


4.-(2) Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 80mA (DC)



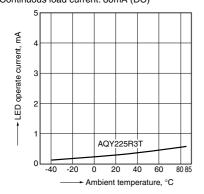
5.-(1) LED operate current vs. ambient temperature characteristics Load voltage: 10V (DC); Continuous load current: 400mA (DC)



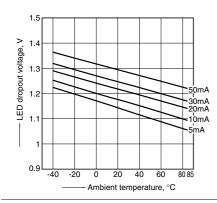
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# RF VSSOP 1 Form A C×R (AQY22OOOT)

5.-(2) LED operate current vs. ambient temperature characteristics Load voltage: 10V (DC); Continuous load current: 80mA (DC)

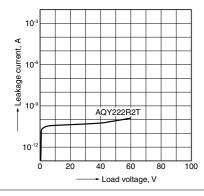


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



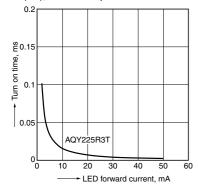
9.-(1) Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C  $77^\circ\text{F}$ 



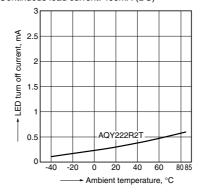
10.-(2) Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: 10V (DC); Continuous load current: 80mA (DC); Ambient temperature: 25°C 77°F



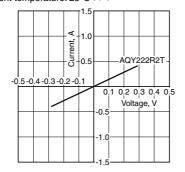
6.-(1) LED turn off current vs. ambient temperature characteristics

Load voltage: 10V (DC); Continuous load current: 400mA (DC)



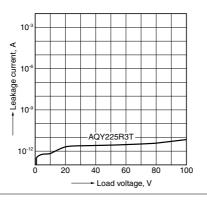
8.-(1) Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



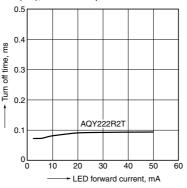
9.-(2) Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C  $77^\circ\text{F}$ 



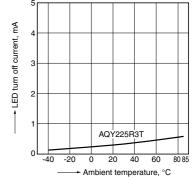
11.-(1) Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: 10V (DC); Continuous load current: 100mA (DC); Ambient temperature: 25°C 77°F



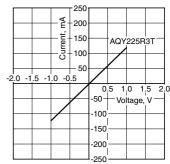
6.-(2) LED turn off current vs. ambient temperature characteristics Load voltage: 10V (DC);

Continuous load current: 80mA (DC)



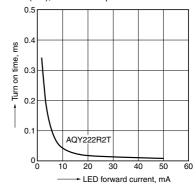
8.-(2) Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



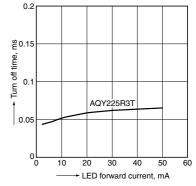
10.-(1) Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: 10V (DC); Continuous load current: 100mA (DC); Ambient temperature: 25°C 77°F



11.-(2) Turn off time vs. LED forward current characteristics

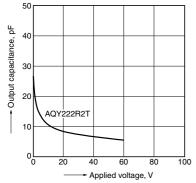
Measured portion: between terminals 3 and 4; Load voltage: 10V (DC); Continuous load current: 80mA (DC); Ambient temperature: 25°C 77°F



12.-(1) Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F





characteristics Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F 10 8

12.-(2) Output capacitance vs. applied voltage

